

IFW



TRANSMITTAL OF FORMAL DRAWINGS

Docket No.
BUR920040015US1 (17427)

Inventor's Name: **Matthew J. Breitwisch, et al.**

Application No.	Filing Date	Confirmation No.	Examiner	Customer No.	Group Art Unit
10/710,821	August 5, 2004	6753	Unassigned	23389	2812

Invention: **ISOLATED FULLY DEPLETED SILICON-ON-INSULATOR REGIONS BY SELECTIVE ETCH**

Address to:
**Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450**

Transmitted herewith are:

3 sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).


Signature

**Leslie S. Szivos, Ph.D.
Registration No. 39,394**

Dated: **March 22, 2005**

I certify that this document and attached formal drawings are being deposited on 03/22/05 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.


Signature of Person Mailing Correspondence

Leslie S. Szivos, Ph.D.

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